

HIGH SPEED PWM CONTROLLER

FEATURES

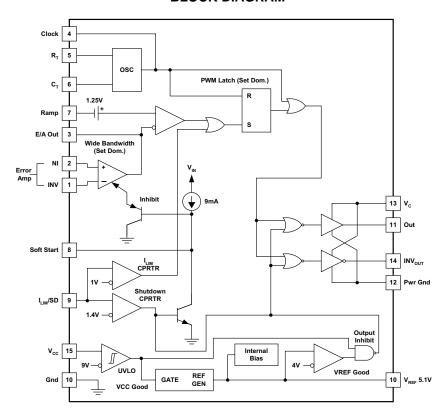
- Complementary Outputs
- Practical Operation Switching Frequencies to 1 MHz
- 50-ns Propagation Delay to Output
- High Current Dual Totem Pole Outputs (1.5 A Peak)
- Wide Bandwidth Error Amplifier
- Fully Latched Logic With Double Pulse Suppression
- Pulse-by-Pulse Current Limiting
- Soft Start/Maximum Duty Cycle Control
- Under-Voltage Lockout with Hysteresis
- Low Start Up Current (1.1 mA)
- Trimmed Bandgap Reference (5.1 V ± 1%)

DESCRIPTION

The UC1824 family of PWM control devices is optimized for high frequency switched mode power supply applications. Particular care was given to minimizing propagation delays through the comparators and logic circuitry while maximizing bandwidth and slew rate of the error amplifier. This controller is designed for use in either current mode or voltage mode systems with the capability for input voltage feed-forward.

Protection circuitry includes a current limit comparator with a 1-V threshold, a TTL compatible shutdown port, and a soft-start pin which doubles as a maximum duty cycle clamp. The logic is fully latched to provide jitter free operation and prohibit multiple pulses at an output. An under-voltage lockout section with 800 mV of hysteresis assures low start up current. During under-voltage lockout, the outputs are high impedance.

BLOCK DIAGRAM





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DESCRIPTION (CONTINUED)

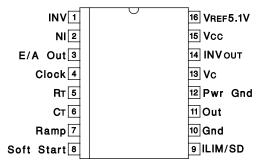
These devices feature totem pole outputs designed to source and sink high peak currents from capacitive loads, such as the gate of a power MOSFET. The on state is designed as a high level.

ABSOLUTE MAXIMUM RATINGS(1)(2)

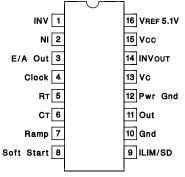
	VALUE	UNIT
Supply voltage (pins 13, 15)	30	V
Output current, source or sink (pins 11, 14)		- 1
DC	0.5	
Pulse (0.5 ms)	2	A
Analog inputs	·	·
(Pins 1, 2, 7)	-0.3 TO 7	
(Pin 8, 9)	-0.3 TO 6	V
Clock output current (pin 4)	-5	
Error amplifier output current (pin 3)	5	
Soft start sink current (pin 8)	20	mA
Oscillator charging current (pin 5)	- 5	
Power dissipation	1	W
Storage temperature range	-65 to 150	00
Lead temperature (soldering, 10 seconds)	300	°C

- (1) All voltages are with respect to GND (Pin 10); all currents are positive into, negative out of part; pin numbers refer to DIL-16 package.
- (2) Consult Unitrode Integrated Circuit Databook for thermal limitations and considerations of package.

SOIC-16 DW PACKAGE (TOP VIEW)



DIL-16 J OR N PACKAGE (TOP VIEW)





PLCC-20 AND LCC-20 Q AND L PACKAGES (TOP VIEW)

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Į		9	10	11	12	13		

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ELECTRICAL CHARACTERISTICS

Unless otherwise stated, these specifications apply for, R_T = 3.65k, C_T = 1 nF, V_{CC} = 15 V, -55°C < T_A < 125°C for the UC1824, -40°C < T_A < 85°C for the UC2824, and 0°C < T_A < 70°C for the UC3824, T_A = T_J .

PARAMETER	TEST CONDITIONS		UC1824 UC2824			UC3824		UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	•
Reference Section								
Output voltage	T _J = 25°C, I _O = 1 mA	5.05	5.10	5.15	5	5.10	5.20	V
Line regulation	10 V < V _{CC} < 30 V		2	20		2	20	>/>
Load regulation	1 mA < I _O < 10 mA		5	20		5	20	mV m\
Temperature stability ⁽¹⁾	$T_{MIN} < T_A < T_{MAX}$		0.2	0.4		0.2	0.4	mV/°C
Total output variation (1)	Line, Load, Temperature	5		5.20	4.95		5.25	V
Output noise voltage ⁽¹⁾	10 Hz < f < 10 kHz		50			50		μV
long term stability ⁽¹⁾	T _J = 125°C, 1000 hrs.		5	25		5	25	mV
Short circuit current	V _{REF} = 0 V	-15	-50	-100	-15	-50	-100	mA
Oscillator Section								
Initial accuracy ⁽¹⁾	T _J = 25°C	360	400	440	360	400	440	kHz
Voltage stability ⁽¹⁾	10 V < V _{CC} < 30 V		0.2%	2%		0.2%	2%	
Temperature stability ⁽¹⁾	$T_{MIN} < T_A < T_{MAX}$		5%			5%		
Total variation ⁽¹⁾	Line, Temperature	340		460	340		460	kHz
Clock out high	·	3.9	4.5		3.9	4.5		
Clock out low			2.3	2.9		2.3	2.9	
Ramp peak ⁽¹⁾		2.6	2.8	3	2.6	2.8	3	V
Ramp valley ⁽¹⁾		0.7	1	1.25	0.7	1	1.25	
Ramp valley to peak ⁽¹⁾		1.6	1.8	2	1.6	1.8	2	
Error Amplifier Section								
Input offset voltage				10			15	mV
Input bias current			0.6	3		0.6	3	μA
Input offset current			0.1	1		0.1	1	μA
Open loop gain	1 V < V _O < 4 V	60	95		60	95		<u>'</u>
CMRR	1.5 V < V _{CM} < 5.5 V	75	95		75	95		dB
PSRR	10 V < V _{CC} < 30 V	85	110		85	110		
Output sink current	V _{PIN 3} = 1 V	1	2.5		1	2.5		
Output source current	V _{PIN 3} = 4 V	-0.5	-1.3		-0.5	-1.3		mA
Output high voltage	I _{PIN 3} = -0.5 mA	4	4.7	5	4	4.7	5	
Output low voltage	I _{PIN 3} = 1 mA	0	0.5	1	0	0.5	1	V
Unity gain bandwidth ⁽¹⁾	1117.5	3	5.5		3	5.5		MHz
Slew rate ⁽¹⁾		6	12		6	12		V/µs
PWM Comparator Section								. 12
Pin 7 bias current	V _{PIN 7} = 0 V		-1	-5		-1	-5	μA
Duty cycle range		0		80	0		85	%
Pin 3 zero dc threshold	V _{PIN 7} = 0 V	1.1	1.25		1.1	1.25		V
Delay to output ⁽¹⁾			50	80		50	80	ns
Soft-Start Section	1							
Charge current	V _{PIN 8} = 0.5 V	3	9	20	3	9	20	μA
Discharge current	V _{PIN 8} = 1 V	1			1			mA
Current Limit/Shutdown Se								
Pin 9 bias current	0 < V _{PIN 9} < 4 V			15			10	μA

⁽¹⁾ This parameter not 100% tested in production but guaranteed by design.



ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise stated, these specifications apply for, R_T = 3.65k, C_T = 1 nF, V_{CC} = 15 V, -55°C < T_A < 125°C for the UC1824, -40°C < T_A < 85°C for the UC2824, and 0°C < T_A < 70°C for the UC3824, T_A = T_J .

PARAMETER	TEST CONDITIONS		UC1824 UC2824			UNIT			
		MIN	TYP	MAX	MIN	TYP	MAX		
Current limit threshold		0.9	1	1.1	0.9	1	1.1	V	
Shutdown threshold		1.25	1.40	1.55	1.25	1.40	1.55	V	
Delay to output			50	80		50	80	ns	
Output Section									
Output low lovel	I _{OUT} = 20 mA		0.25	0.40		0.25	0.40		
Output low level	I _{OUT} = 200 mA		1.2	2.2		1.2	2.2	V	
Outmout bimb lavel	I _{OUT} = -20 mA	13	13.5		13	13.5			
Output high level	I _{OUT} = -200 mA	12	13		12	13			
Collector leakage	V _C = 30 V		100	500		10	500	μΑ	
Rise/fall time (2)	CL = 1 nF		30	60		30	60	ns	
Under-Voltage Lockout Sec	etion								
Start threshold		8.8	9.2	9.6	8.8	9.2	9.6	V	
UVLO hysteresis		0.4	8.0	1.2	0.4	0.8	1.2	V	
Supply Current Section							1		
Start up current	V _{CC} = 8 V		1.1	2.5		1.1	2.5	A	
ICC	V _{PIN 1} , V _{PIN 7} , V _{PIN 9} = 0 V; V _{PIN 2} = 1 V		22	33		22	33	mA	

⁽²⁾ This parameter not 100% tested in production but guaranteed by design.

UC1824 Printed Circuit Board Layout Considerations

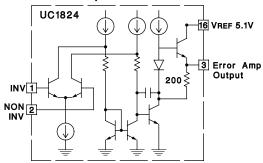
High speed circuits demand careful attention to layout and component placement. To assure proper performance of the UC1824 follow these rules:

- 1. Use a ground plane.
- 2. Damp or clamp parasitic inductive kick energy from the gate of driven MOSFETs. Do not allow the output pins to ring below ground. A series gate resistor or a shunt 1-A Schottky diode at the output pin serves this purpose.
- 3. Bypass V_{CC} , V_C , and V_{REF} . Use 0.1- μ F monolithic ceramic capacitors with low equivalent series inductance. Allow less than 1 cm of total lead length for each capacitor between the bypassed pin and the ground plane.
- 4. Treat the timing capacitor, C_T, like a bypass capacitor.

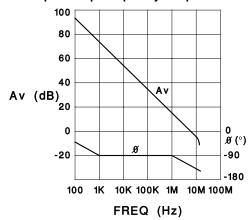


Error Amplifier Circuit

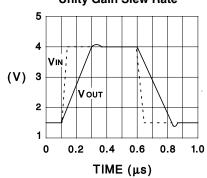
Simplified Schematic



Open Loop Frequency Response

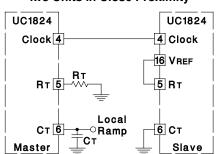


Unity Gain Slew Rate

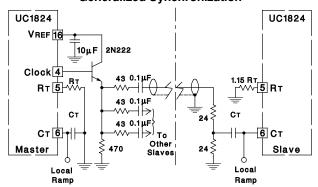


Synchronized Operation

Two Units in Close Proximity

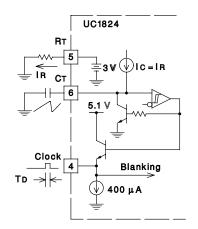


Generalized Synchronization

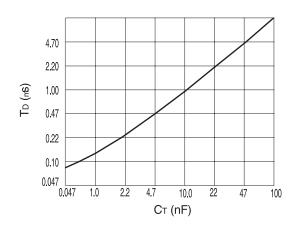




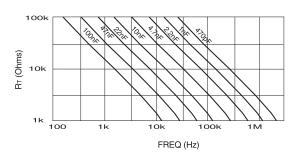
Oscillator Circuit



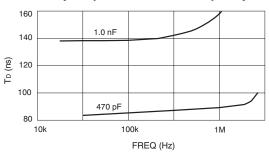
Primary Output Deadtime vs C_T (3k $\leq R_T \leq$ 100k)



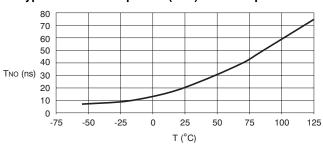
Timing Resistance vs Frequency



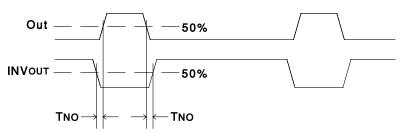
Primary Output Deadtime vs Frequency



Typical Non-Overlap Time (TNO) Over Temperature

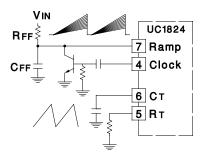


Non-Overlap Time (TNO)



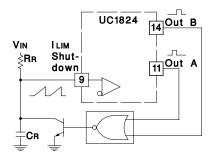


Forward Technique for Off-Line Voltage Mode Application

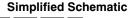


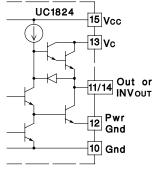
Constant Volt-Second Clamp Circuit

The circuit shown here will achieve a constant volt-second product clamp over varying input voltages. The ramp generator components, RT and CR are chosen so that the ramp at Pin 9 crosses the 1V threshold at the same time the desired maximum volt-second product is reached. The delay through the functional nor block must be such that the ramp capacitor can be completely discharged during the minimum deadtime.

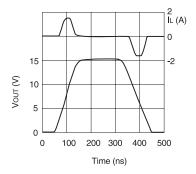


Output Section

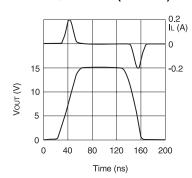




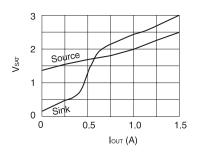
Rise/Fall Time (CL=10 nF)



Rise/Fall Time (CL=1 nF)

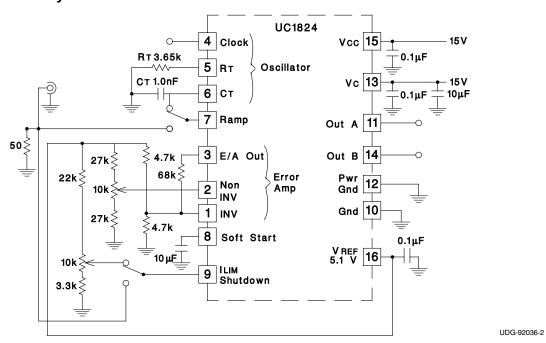


Saturation Curves





Open-Loop Laboratory Test Fixture



UC1824's functions and measuring their specifications.

This test fixture is useful for exercising many of the As with any wideband circuit, careful grounding and bypass procedures should be followed. The use of a ground plane is highly recommended.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
UC2824DW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2824DW
UC2824DW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2824DW
UC2824N	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	UC2824N
UC2824N.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	UC2824N
UC3824DW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3824DW
UC3824DW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3824DW
UC3824DWTR	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3824DW
UC3824DWTR.A	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3824DW
UC3824N	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	UC3824N
UC3824N.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	UC3824N

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC3824DWTR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
UC3824DWTR	SOIC	DW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
UC2824DW	DW	SOIC	16	40	507	12.83	5080	6.6
UC2824DW.A	DW	SOIC	16	40	507	12.83	5080	6.6
UC2824N	N	PDIP	16	25	506	13.97	11230	4.32
UC2824N.A	N	PDIP	16	25	506	13.97	11230	4.32
UC3824DW	DW	SOIC	16	40	507	12.83	5080	6.6
UC3824DW.A	DW	SOIC	16	40	507	12.83	5080	6.6
UC3824N	N	PDIP	16	25	506	13.97	11230	4.32
UC3824N.A	N	PDIP	16	25	506	13.97	11230	4.32

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